

Optocoupler, Phototransistor Output (Dual, Quad Channel)

Features

- Current Transfer Ratio at $I_F = 10 \text{ mA}$
- Isolation Test Voltage, 5300 V_{RMS}
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- CSA 93751
- BSI IEC60950 IEC60065
- DIN EN 60747-5-2 (VDE0884)
DIN EN 60747-5-5 pending
Available with Option 1
- FIMKO

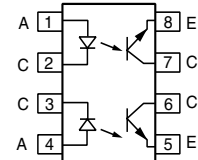
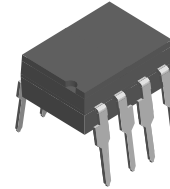
Description

The ILD1/ 2/ 5/ ILQ1/ 2/ 5 are optically coupled isolated pairs employing GaAs infrared LEDs and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the drive while maintaining a high degree of electrical isolation between input and output. The ILD1/ 2/ 5/ ILQ1/ 2/ 5 are especially

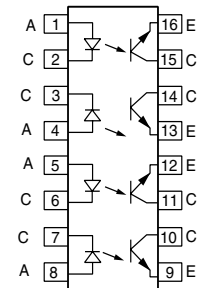
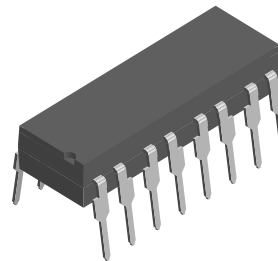
designed for driving medium-speed logic and can be used to eliminate troublesome ground loop and noise problems. Also these couplers can be used to replace relays and transformers in many digital interface applications such as CTR modulation.

The ILD1/ 2/ 5 has two isolated channels in a single DIP package and the ILQ1/ 2/ 5 has four isolated channels per package.

Dual Channel



Quad Channel



1179012



Order Information

Part	Remarks
ILD1	CTR > 20 %, DIP-8
ILQ1	CTR > 20 %, DIP-16
ILD2	CTR > 100 %, DIP-8
ILQ2	CTR > 100 %, DIP-16
ILD5	CTR > 50 %, DIP-8
ILQ5	CTR > 50 %, DIP-16
ILD1-X007	CTR > 20 %, SMD-8 (option 7)
ILD1-X009	CTR > 20 %, SMD-8 (option 9)
ILD2-X006	CTR > 100 %, DIP-8 400 mil (option 6)
ILD2-X007	CTR > 100 %, SMD-8 (option 7)
ILD2-X009	CTR > 100 %, SMD-8 (option 9)
ILD5-X009	CTR > 50 %, SMD-8 (option 9)
ILQ1-X009	CTR > 20 %, SMD-16 (option 9)
ILQ2-X009	CTR > 100 %, SMD-16 (option 9)

For additional information on the available options refer to Option Information.

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	6.0	V
Forward current		I_F	60	mA
Surge current		I_{FSM}	2.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.3	mW/°C

Output

Parameter	Test condition	Part	Symbol	Value	Unit
Collector-emitter reverse voltage		ILD1	V_{CER}	50	V
		ILQ1	V_{CER}	50	V
		ILD2	V_{CER}	70	V
		ILQ2	V_{CER}	70	V
		ILD5	V_{CER}	70	V
		ILQ5	V_{CER}	70	V
Collector current			I_C	50	mA
	$t < 1.0\text{ ms}$		I_C	400	mA
Power dissipation			P_{diss}	200	mW
Derate linearly from 25 °C				2.6	mW/°C

Coupler

Parameter	Test condition	Symbol	Value	Unit
Isolation test voltage (between emitter and detector referred to standard climate 25 °C/ 50 % RH, DIN 50014)		V_{ISO}	5300	V_{RMS}
Creepage			≥ 7.0	mm
Clearance			≥ 7.0	mm
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	10^{12}	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	10^{11}	Ω
Package power dissipation		P_{tot}	250	mW
Derate linearly from 25 °C			3.3	mW/°C
Storage temperature		T_{stg}	- 40 to + 150	°C
Operating temperature		T_{amb}	- 40 to + 100	°C
Junction temperature		T_j	100	°C
Soldering temperature	2.0 mm from case bottom	T_{sld}	260	°C



Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Input

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 60\text{ mA}$	V_F		1.25	1.65	V
Reverse current	$V_R = 6.0\text{ V}$	I_R		0.01	10	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$	C_O		25		pF
Thermal resistance, junction to lead		T_{thJL}		750		K/W

Output

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter capacitance	$V_{CE} = 5.0\text{ V}$, $f = 1.0\text{ MHz}$	C_{CE}		6.8		pF
Collector-emitter leakage current	$V_{VCE} = 10\text{ V}$	I_{CEO}		5.0	50	nA
Saturation voltage, collector-emitter	$I_{CE} = 1.0\text{ mA}$, $I_B = 20\text{ }\mu\text{A}$	V_{CESAT}		0.25	0.4	V
DC forward current gain	$V_{CE} = 10\text{ V}$, $I_B = 20\text{ }\mu\text{A}$	HFE	200	650	1800	
DC forward current gain saturated	$V_{CE} = 0.4\text{ V}$, $I_B = 20\text{ }\mu\text{A}$	HFE_{sat}	120	400	600	
Thermal resistance, junction to lead		R_{thjL}		500		K/W

Coupler

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Capacitance (input-output)	$V_{IO} = 0\text{ V}$, $f = 1.0\text{ MHz}$	C_{IO}		0.8		pF

Current Transfer Ratio

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Current Transfer Ratio (collector-emitter saturated)	$I_F = 10\text{ mA}$, $V_{CE} = 0.4\text{ V}$	ILD1 ILQ1	CTR_{CEsat}		75		%
		ILD2 ILQ2	CTR_{CEsat}		170		%
		ILD5 ILQ5	CTR_{CEsat}		100		%
Current Transfer Ratio (collector-emitter)	$I_F = 10\text{ mA}$, $V_{CE} = 10\text{ V}$	ILD1 ILQ1	CTR_{CE}	20	80	300	%
		ILD2 ILQ2	CTR_{CE}	100	200	500	%
		ILD5 ILQ5	CTR_{CE}	50	130	400	%

Typical Switching Times

Non-saturated Switching Timing

Parameter	Current	Delay	Rise time	Storage	Fall time	Propagation H-L	Propagation L-H
Test condition	$V_{CE} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}						
Symbol	I_F	t_D	t_r	t_s	t_f	t_{PHL}	t_{PLH}
Unit	mA	μs	μs	μs	μs	μs	μs
ILD1 ILQ1	20	0.8	1.9	0.2	1.4	0.7	1.4
ILD2 ILQ2	5.0	1.7	2.6	0.4	2.2	1.2	2.3
ILD5 ILQ5	10	1.7	2.6	0.4	2.2	1.1	2.5

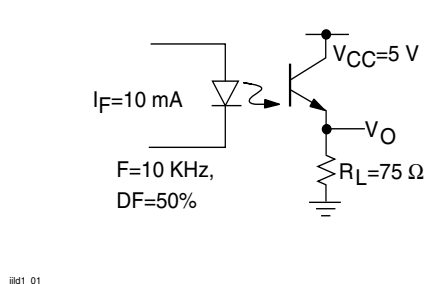
Saturated Switching Timing

Parameter	Current	Delay	Rise time	Storage	Fall time	Propagation H-L	Propagation L-H
Test condition	$V_{CE} = 0.4 \text{ V}$, $R_L = 1.0 \text{ k}\Omega$, $V_{CC} = 5.0 \text{ V}$, $V_{TH} = 1.5 \text{ V}$						
Symbol	I_F	t_D	t_r	t_s	t_f	t_{PHL}	t_{PLH}
Unit	mA	μs	μs	μs	μs	μs	μs
ILD1 ILQ1	20	0.8	1.2	7.4	7.6	1.6	8.6
ILD2 ILQ2	5.0	1.0	2.0	5.4	13.5	5.4	7.4
ILD5 ILQ5	10	1.7	7.0	4.6	20	2.6	7.2

Common Mode Transient Immunity

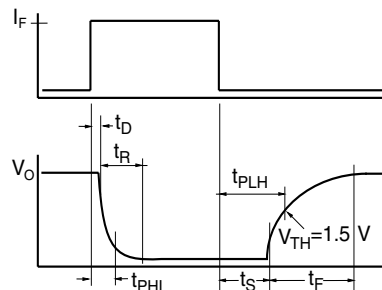
Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Common mode rejection, output high	$V_{CM} = 50 \text{ V}_{P-P}$, $R_L = 1.0 \text{ k}\Omega$, $I_F = 0 \text{ mA}$	CM_H		5000		V/ μs
Common mode rejection, output low	$V_{CM} = 50 \text{ V}_{P-P}$, $R_L = 1.0 \text{ k}\Omega$, $I_F = 10 \text{ mA}$	CM_L		5000		V/ μs
Common mode coupling capacitance		C_{CM}		0.01		pF

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)



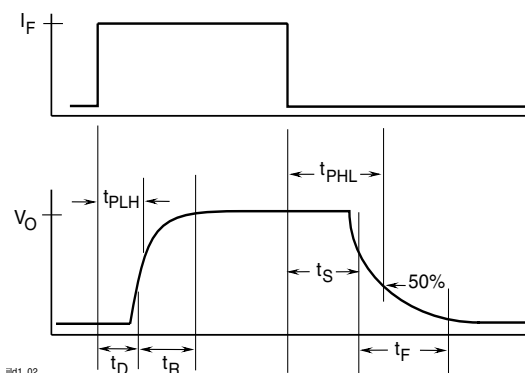
ild1_01

Figure 1. Non-saturated Switching Schematic



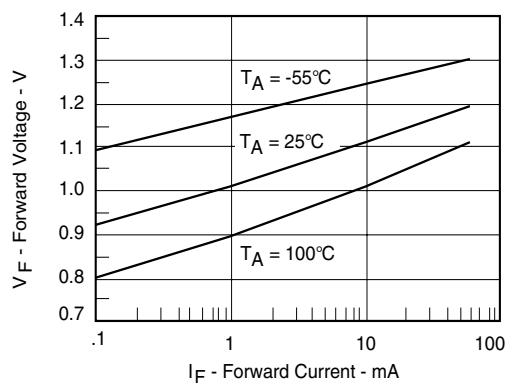
ild1_04

Figure 4. Saturated Switching Timing



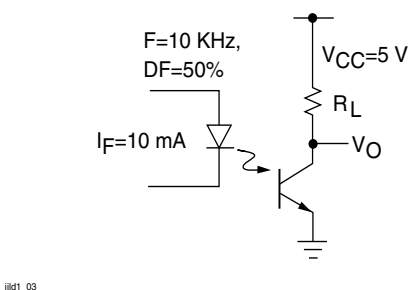
ild1_02

Figure 2. Non-saturated Switching Timing



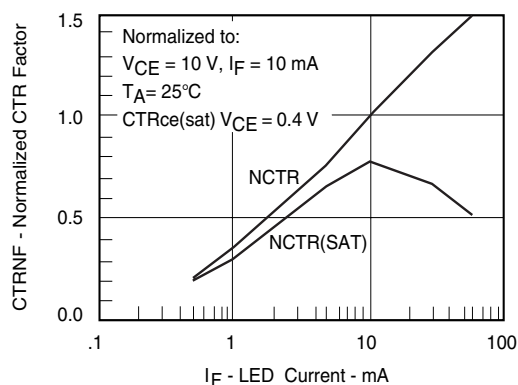
ild1_05

Figure 5. Normalized Non-Saturated and Saturated CTR vs. LED Current



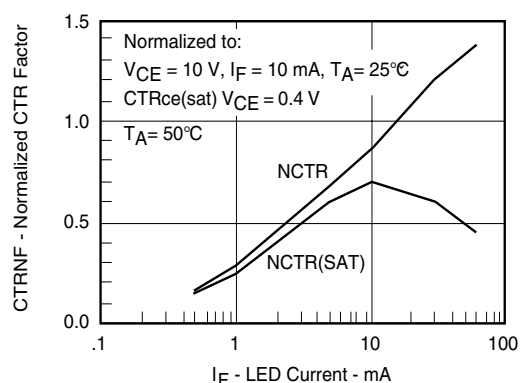
ild1_03

Figure 3. Saturated Switching Schematic



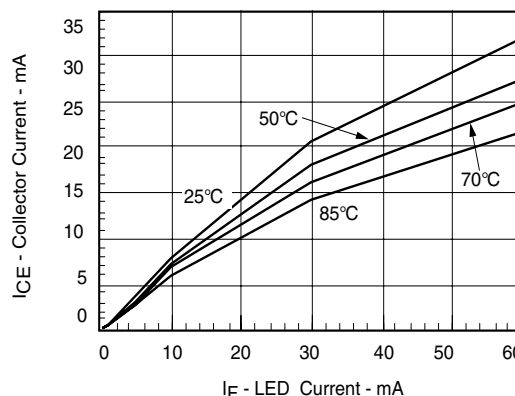
ild1_06

Figure 6. Normalized Non-Saturated and Saturated CTR vs. LED Current



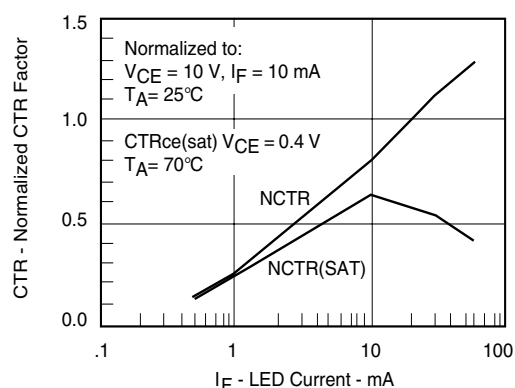
ild1_07

Figure 7. Normalized Non-Saturated and Saturated CTR vs. LED Current



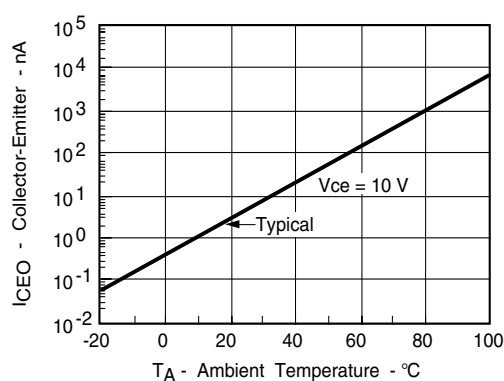
ild1_10

Figure 10. Collector-Emitter Current vs. Temperature and LED Current



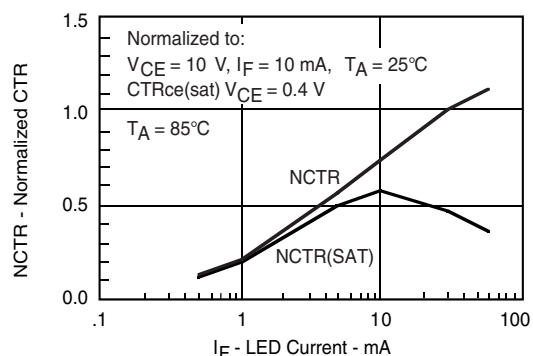
ild1_08

Figure 8. Normalized Non-Saturated and Saturated CTR vs. LED Current



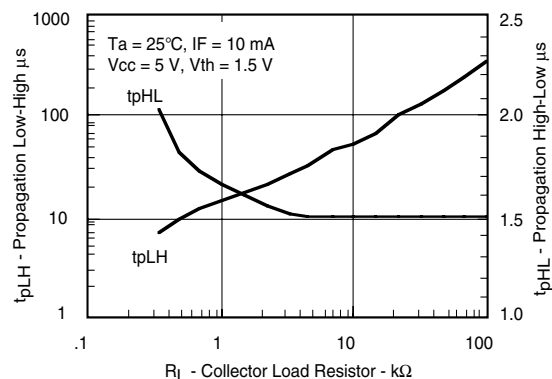
ild1_11

Figure 11. Collector-Emitter Leakage Current vs. Temp.



ild1_09

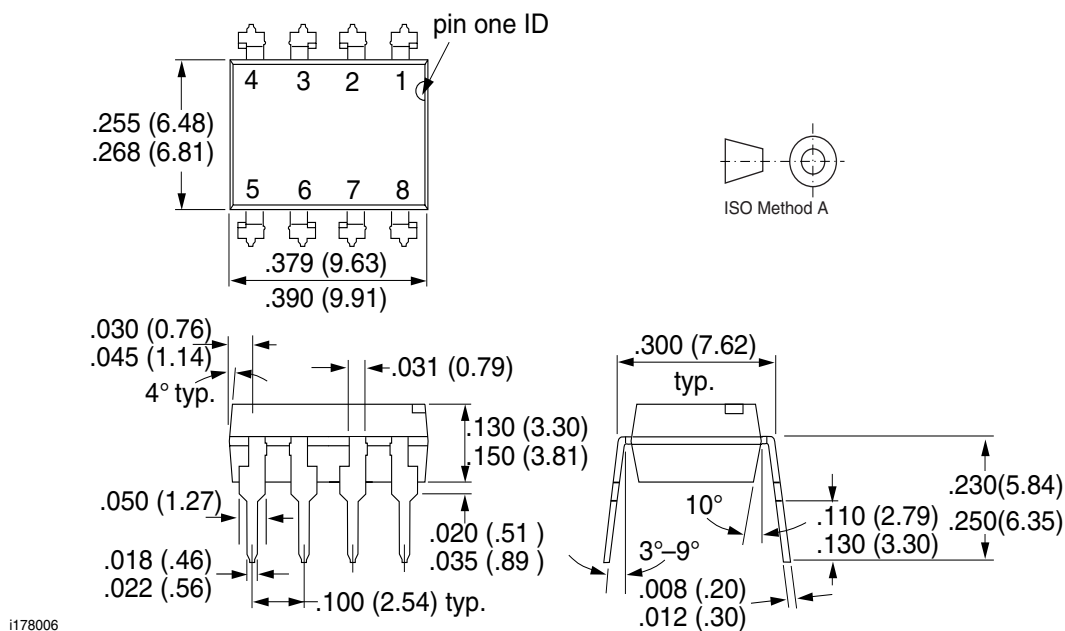
Figure 9. Normalized Non-Saturated and Saturated CTR vs. LED Current



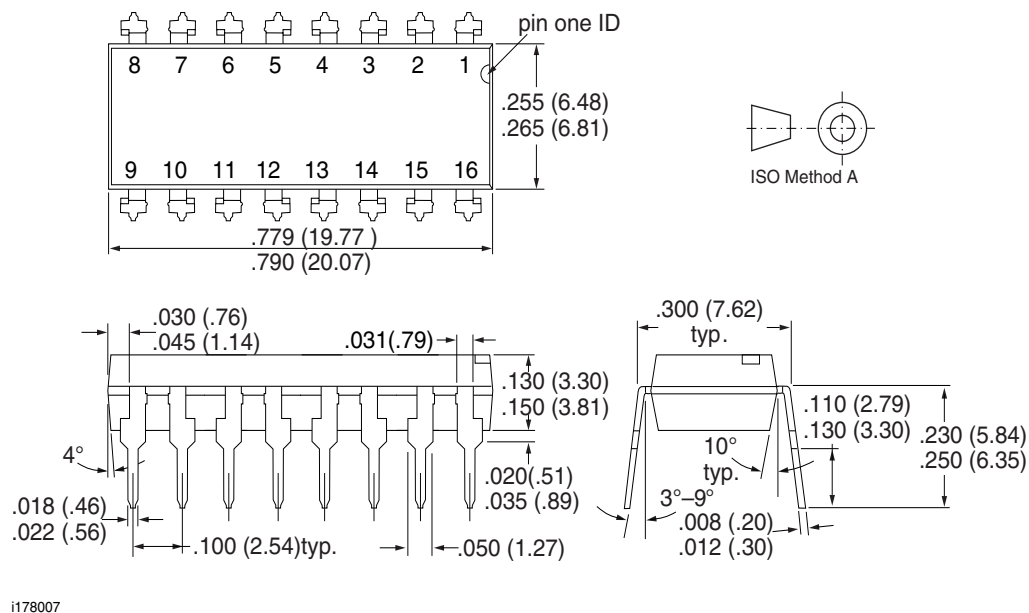
ild1_12

Figure 12. Propagation Delay vs. Collector Load Resistor

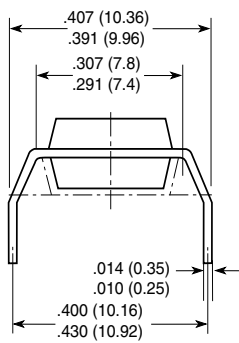
Package Dimensions in Inches (mm)



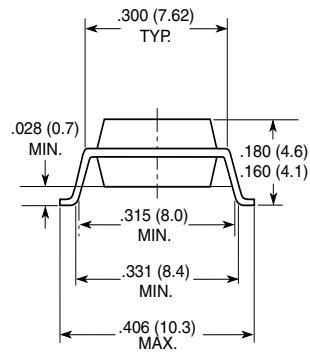
Package Dimensions in Inches (mm)



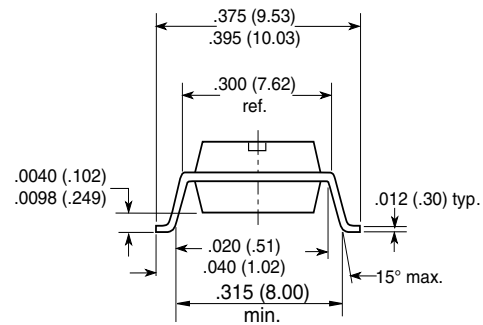
Option 6



Option 7



Option 9



18450



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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JONHON

«JONHON» (основан в 1970 г.)

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(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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